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5,000 Watt Transient Voltage Suppressor (TVS) Protection Device

Screening in reference to MIL-PRF-19500 available

DESCRIPTION

This Transient Voltage Suppressor series M5KP5.0A – M5KP110CA provides a range of standoff voltage options from 5.0 to 110 V in unidirectional, bidirectional, RoHS compliant, and SnPb solder dipped options. Multiple advanced screening levels are available for enhanced reliability. Clamping action is almost instantaneous. As a result, they provide effective protection from ESD or EFT per IEC61000-4-2 and IEC61000-4-4, as well as transients caused by inductive switching and RFI. They also protect from secondary lightning effects per 61000-4-5 at the class levels specified below.

Important: For the latest information, visit our website http://www.microsemi.com.

FEATURES

- Available in both unidirectional and bidirectional configurations
- 3σ lot norm screening performed on standby current I_D
- 100% surge tested devices
- Various screening in reference to MIL-PRF-19500. Refer to <u>HiRel Non-Hermetic Product Portfolio</u> for more details on the screening options
 (See part nomenclature for all options.)
- High reliability controlled devices with wafer fabrication and assembly lot traceability
- Moisture classification is level 1 with no dry pack required per IPC/JEDEC J-STD-020B
- RoHS compliant versions are available

- Selections for 5.0 to 110 volts stand-off voltage (V_{WM})
- Economical TVS series for thru-hole mounting
- This M5KPxxx series has a significantly reduced body diameter than the 5KPxxx commercial series for a smaller size footprint often required for aviation and other applications

APPLICATIONS / BENEFITS

- Pico- to nano-second response time
- Protection from transients due to inductive switching and RFI
- Compliant to IEC 61000-4-2 and IEC 61000-4-4 for ESD and EFT protection respectively
- Secondary lightning protection per IEC61000-4-5 with 42 ohms source impedance:

Class 1, 2, 3, 4: M5KP5.0A to M5KP110CA

Class 5: M5KP5.0A to M5KP110CA (short distance)

Class 5: M5KP5.0A to M5KP36CA (long distance)

• Secondary lightning protection per IEC61000-4-5 with 12 ohms source impedance:

Class 1 & 2: M5KP5.0A to M5KP110CA

Class 3: M5KP5.0A to M5KP78CA

Class 4: M5KP5.0A to M5KP40CA

• Secondary lightning protection per IEC61000-4-5 with 2 ohms source impedance:

Class 2: M5KP5.0A to M5KP70CA

Class 3: M5KP5.0A to M5KP36CA

Class 4: M5KP5.0A to M5KP18CA



Also available in:

P600 package

(commercial plastic axial-leaded)



5KP5.0e3 - 5KP250CAe3

DO-13 package

(metal axial-leaded)

LC6.5A - LC170A

MSC – Lawrence

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MAXIMUM RATINGS @ 25 °C unless otherwise noted

Parameters/Test Conditions	Symbol	Value	Unit
Junction and Storage Temperature	T_J and T_{STG}	-65 to +150	°C
Thermal Resistance, Junction to Lead @ 0.375 inch (9.5 mm) lead length from body	R _{OJL}	20	°C/W
Thermal Resistance, Junction to Ambient (1)	R _{OJA}	80	°C/W
Peak Pulse Power Dissipation (2) 10/1000 μs	P _{PP}	5000	W
Steady-State Power Dissipation @ T _L = 25 °C 0.375 inch (9.5 mm) from body	P _D	6 1.56 ⁽¹⁾	W
T _{clamping} (0 volts to V _(BR) min, theoretical) Unidirectional		< 100	ps
Bidirectional		< 5	ns
Forward Voltage (3)	V _F	3.5	V
Solder Temperature @ 10 s		260	°C

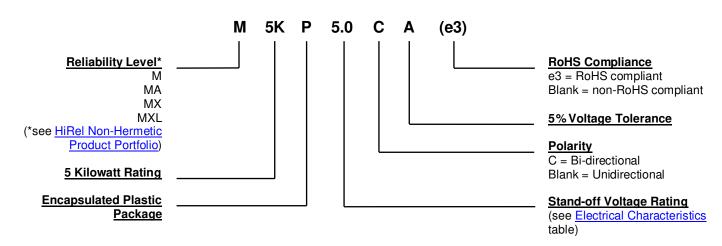
Notes: 1. When mounted on FR4 PC board with 4 mm² copper pads (1 oz) and track width 1 mm, length 25 mm.

- 2. With impulse repetition rate (duty factor) of 0.01 % or less (also Figure 1 and 2).
- 3. At 100 amp peak impulse of 8.3 ms half-sine wave (unidirectional only).

MECHANICAL and PACKAGING

- CASE: Void-free transfer molded thermosetting epoxy body meeting UL94V-0
- TERMINALS: Tin-lead or RoHS compliant annealed matte-tin plating. Solderable per MIL-STD-750, method 2026.
- MARKING: Part number
- POLARITY: Cathode indicated by band. No cathode band on bidirectional devices.
- TAPE & REEL option: Standard per EIA-296 (add "TR" suffix to part number). Consult factory for quantities.
- WEIGHT: Approximately 1.4 grams
- See <u>Package Dimensions</u> on last page.

PART NOMENCLATURE





	SYMBOLS & DEFINITIONS				
Symbol	Definition				
α _{V(BR)}	Temperature Coefficient of Breakdown Voltage: The change in breakdown voltage divided by the change in temperature that caused it expressed in %/°C or mV/°C.				
V _{WM}	Working Standoff Voltage: The maximum-rated value of dc or repetitive peak positive cathode-to-anode voltage that may be continuously applied over the standard operating temperature.				
P _{PP}	Peak Pulse Power. The rated random recurring peak impulse power or rated nonrepetitive peak impulse power. The impulse power is the maximum-rated value of the product of IPP and V _C .				
V _(BR)	Breakdown Voltage: The voltage across the device at a specified current I _(BR) in the breakdown region.				
I _D	Standby Current: The current through the device at rated stand-off voltage.				
I _{PP}	Peak Impulse Current: The maximum rated random recurring peak impulse current or nonrepetitive peak impulse current that may be applied to a device. A random recurring or nonrepetitive transient current is usually due to an external cause, and it is assumed that its effect will have completely disappeared before the next transient arrives.				
Vc	Clamping Voltage: The voltage across the device in a region of low differential resistance during the application of an impulse current (I _{PP}) for a specified waveform.				
I _(BR)	Breakdown Current: The current used for measuring Breakdown Voltage V _(BR) .				



ELECTRICAL CHARACTERISTICS @ 25 °C

	DEVEDOE	DDE 4KD					BAAVIBALIBA
	REVERSE STAND-	BREAKDO		MAXIMUM CLAMPING	MAXIMUM STANDBY	MAXIMUM PEAK PULSE	MAXIMUM TEMPERATURE
	OFF	VOLTAC	a⊑ I _(BR)	VOLTAGE	CURRENT ID	CURRENT	COEFFICIENT OF
PART NUMBER	VOLTAGE	▼ (BH) ©	•(BH)	V _C @ I _{PP}	@ V _{wm}	Ipp	V _(BR)
(Note 2)	V _{wm}				G - WW	(FIG. 2)	α _{V(BR)}
	(Note 1)						, ,
	٧	V	mA	V	μ Α	Α	mV/ ºC
M5KP5.0A	5.0	6.40 - 7.00	50	9.2	2000*	543	4.0
M5KP6.0A	6.0	6.67 - 7.37	50	10.3	5000	485	4.0
M5KP6.5A	6.5	7.22 - 7.98	50	11.2	2000	447	4.0
M5KP7.0A	7.0	7.78 - 8.60	50	12.0	1000	417	5.0
M5KP7.5A	7.5	8.33 – 9.21	5	12.9	250	388	6.0
M5KP8.0A	8.0	8.89 – 9.83	5	13.6	150	367	6.0
M5KP8.5A	8.5	9.44 – 10.4	5	14.4	50	347	7.0
M5KP9.0A	9.0	10.0 – 11.1	5	15.4	20	325	8.0
M5KP10A	10	11.1 – 12.3	5	17.0	15	294	9.0
M5KP11A	11	12.2 – 13.5	5	18.2	10	274	10
M5KP12A	12	13.3 – 14.7	5	19.9	10	251	11
M5KP13A	13	14.4 – 15.9	5	21.5	10	232	12
M5KP14A	14	15.6 – 17.2	5	23.2	10	215	13
M5KP15A	15	16.7 – 18.5	5	24.4	10	206	15
M5KP16A	16	17.8 – 19.7	5	26.0	10	192	16
M5KP17A	17	18.9 – 20.9	5	27.6	10	181	18
M5KP18A	18	20.0 – 22.1	5	29.2	10	172	19
M5KP20A	20	22.2 – 24.5	5	32.4	10	154	22
M5KP22A	22	24.4 – 26.9	5	35.5	10	141	24
M5KP24A	24	26.7 – 29.5	5	38.9	10	128	27
M5KP26A	26	28.9 – 31.9	5	42.1	10	119	29
M5KP28A	28 30	31.1 – 34.4	<u>5</u>	45.5 48.4	10 10	110 103	30 35
M5KP30A	30 33	33.3 – 36.8	5 5	48.4 53.3	10	94	38
M5KP33A	36	36.7 – 40.6 40.0 – 44.2		58.1	10	86	40
M5KP36A M5KP40A	36 40	44.4 – 49.1	5 5	64.5	10	78	40 45
M5KP43A	43	47.8 – 52.8	5	69.4	10	78	49
M5KP45A	45 45	50.0 – 55.3	5	72.7	10	69	51
M5KP48A	48	53.3 – 58.9	5	77.4	10	65	55
M5KP51A	51	56.7 – 62.7	5	82.4	10	61	60
M5KP54A	54	60.0 – 66.3	5	87.1	10	57	64
M5KP58A	58	64.4 – 71.2	5	93.6	10	53	69
M5KP60A	60	66.7 – 73.7	5	96.8	10	52	70
M5KP64A	64	71.1 – 78.6	5	103.0	10	49	75 75
M5KP70A	70	77.8 – 86.0	5	113	10	44	84
M5KP75A	75	83.3 – 92.1	5	121	10	41	90
M5KP78A	78	86.7 – 95.8	5	126	10	40	94
M5KP85A	85	94.4 – 104.0	5	137	10	36	102
M5KP90A	90	100 – 111	5	146	10	34	109
M5KP100A	100	111 – 123	5	162	10	31	122
M5KP110A	110	122 - 135	5	177	10	28	132

NOTES:

- 1. Transient voltage suppressors are normally selected with reverse "stand-off voltage" (Vww) which should be equal to or greater than the dc or continuous peak operating voltage level.
- 2. For the bidirectional M5KP5.0CA double the l_{D} maximum standby current to 4000 μA .



GRAPHS

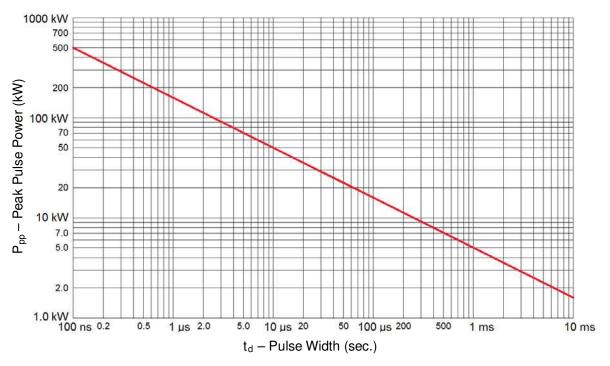


FIGURE 1
Peak Pulse Power Rating Curve

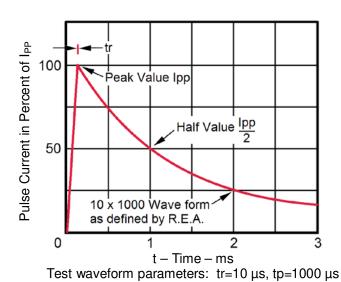


FIGURE 2
Pulse Waveform for 10/1000 µs Exponential Surge



GRAPHS (continued)

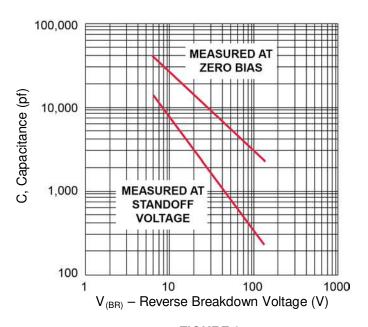
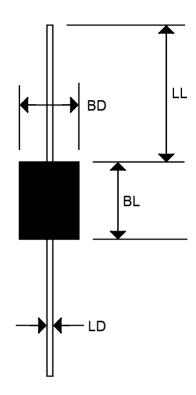


FIGURE 3
Typical Junction Capacitance



PACKAGE DIMENSIONS



	Dimensions					
Dim	In	ch	Millimeters			
	Min	Max	Min	Max		
LL	0.750	-	19.05	-		
BL	0.365	0.385	9.27	9.78		
BD	0.235	0.255	5.97	6.48		
LD	0.047	0.053	1.194	1.346		